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FDS86540 N-Channel PowerTrench[®] MOSFET 60 V, 18 A, 4.5 m Ω

Features

- Max $r_{DS(on)}$ = 4.5 m Ω at V_{GS} = 10 V, I_D = 18 A
- Max $r_{DS(on)} = 5.4 \text{ m}\Omega \text{ at } V_{GS} = 8 \text{ V}, I_D = 16.5 \text{ A}$
- High performance trench technologh for extremely low r_{DS(on)}
- High power and current handing capability in a widely used surface mount package
- 100% UIL Tested
- RoHS Compliant

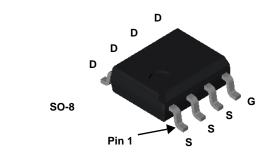


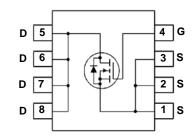
General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(on)}$, fast switching speed and body diode reverse recovery performance.

Applications

- Primary Switch in isolated DC-DC
- Synchronous Rectifier
- Load Switch





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			60	V	
V _{GS}	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous			18		
	-Pulsed			120	Α	
E _{AS}	Single Pulse Avalanche Energy (Note 3)		(Note 3)	194	mJ	
D	Power Dissipation	T _C = 25 °C	(Note 1)	5.0		
PD	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS86540	FDS86540	SO-8	13"	12 mm	2500 units

May 2012

FDS86540
N-Channel
PowerTrench [®]
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
	acteristics			,,		
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	60			V
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		28		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 48 V, V_{GS} = 0 V$			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0 V$			±100	nA
	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2	3.1	4	V
$\Delta V_{GS(th)}$ $\Delta T_{.l}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-11		mV/°C
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 18 A		3.7	4.5	
		V _{GS} = 8 V, I _D = 16.5 A		4.2	5.4	mΩ
		V _{GS} = 10 V, I _D = 18 A, T _J = 125 °C		5.9	7	1
9 _{FS}	Forward Transconductance	$V_{DS} = 10 V$, $I_{D} = 18 A$		69		S
C _{iss} C _{oss} C _{rss} R _g	Input Capacitance Output Capacitance Reverse Transfer Capacitance Gate Resistance	V _{DS} = 30 V, V _{GS} = 0 V, f = 1 MHz		4820 1610 67 0.6	6410 2145 130	pF pF pF Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			28	45	ns
t _r	Rise Time	V _{DD} = 30 V, I _D = 18 A,		15	27	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		33	53	ns
t _f	Fall Time			7.1	15	ns
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		65	90	nC
Qg	Total Gate Charge	$V_{GS} = 0 V to 8 V V_{DD} = 30 V,$		53	75	nC
Q _{gs}	Gate to Source Charge	I _D = 18 A		22		nC
Q _{gd}	Gate to Drain "Miller" Charge			13		nC
Drain-So	urce Diode Characteristics					
V _{SD}	Source-Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 18 A (Note 2)		0.8	1.3	
		$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.7	1.2	V
	1					
t _{rr}	Reverse Recovery Time	I _F = 18 A, di/dt = 100 A/μs		57	92	ns

1. $R_{\theta,JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta,JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

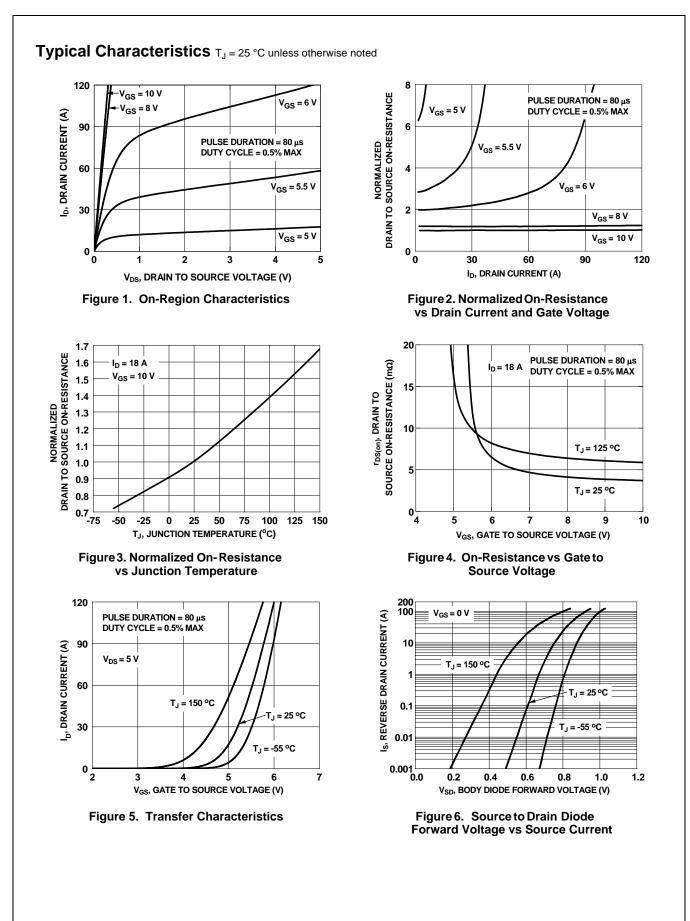


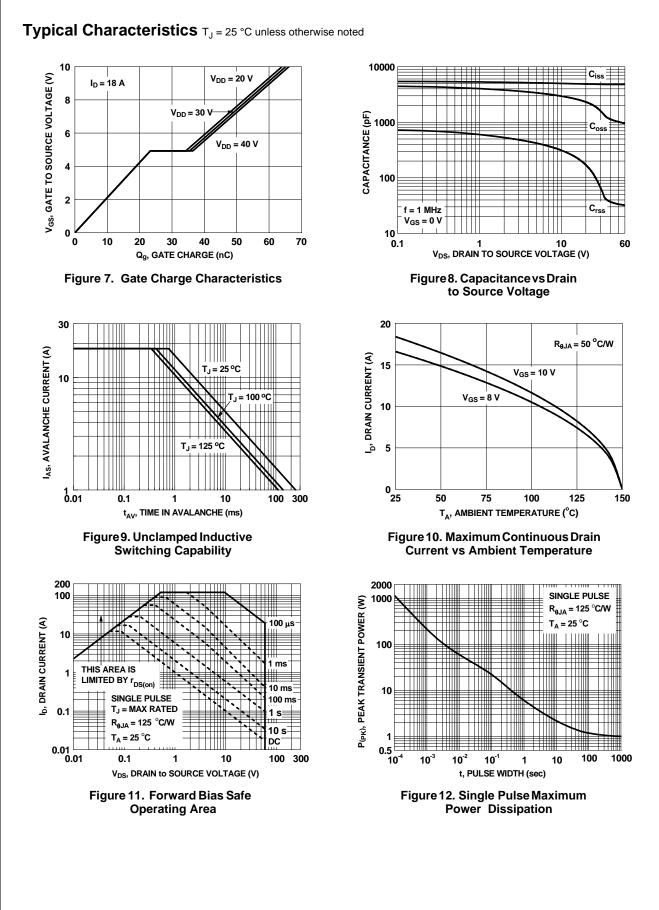
a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



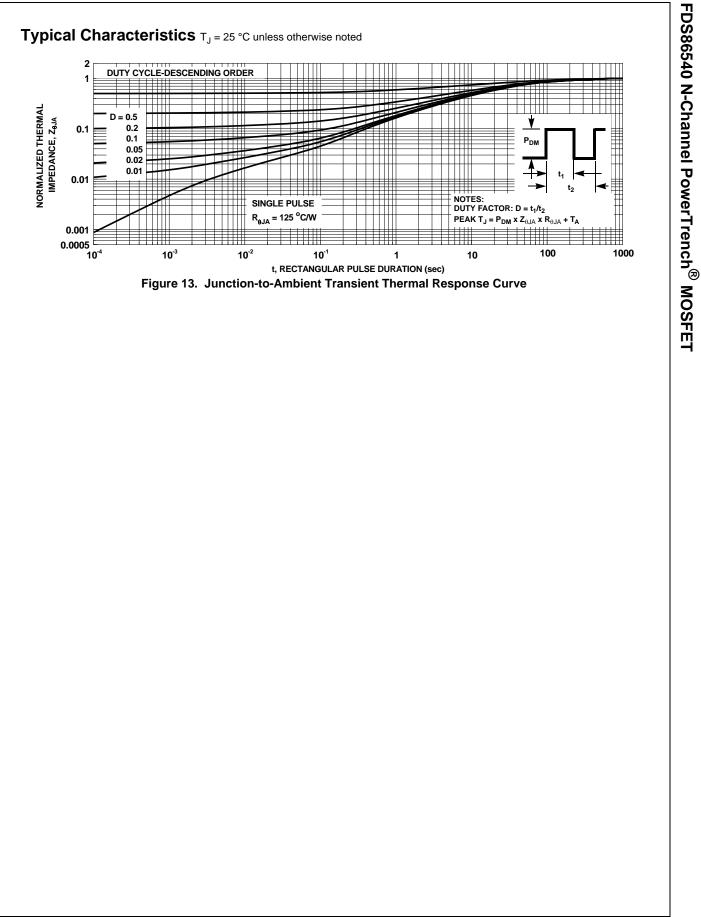
b) 125 °C/W when mounted on a minimum pad.

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%. 3. Starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 36 A, V_{DD} = 54 V, V_{GS} = 10 V.





FDS86540 N-Channel PowerTrench[®] MOSFET





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FDS86540 N-Channel PowerTrench[®] MOSFE



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